

Abstracts

An X-Band 10 W Monolithic Transmit-Receive GaAs FET Switch

Y. Ayasli, R. Mozzi, L. Hanes and L.D. Reynolds. "An X-Band 10 W Monolithic Transmit-Receive GaAs FET Switch." 1982 Microwave and Millimeter-Wave Monolithic Circuits Symposium Digest 82.1 (1982 [MCS]): 42-46.

A monolithic transmit-receive GaAs FET switch capable of switching more than 10 W CW power with about 1 dB insertion loss and 26 dB isolation at X-band frequencies is reported.

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